Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	1583185	source or drain or "source/drain"	US-PGPUB; USPAT	OR	OFF	2005/06/10 15:34
L2	411053	oxidation or oxidizing or oxidized or oxidizes or oxidize	US-PGPUB; USPAT	OR	OFF	2005/06/10 16:05
L3	16030	1 with 2	US-PGPUB; USPAT	OR	OFF	2005/06/10 16:05
L4	32859	tft or "thin film transistor"	US-PGPUB; USPAT	OR	OFF	2005/06/10 16:05
L5	745	3 and 4	US-PGPUB; USPAT	OR	OFF	2005/06/10 16:05
L6	94404	"438"/$.ccls.	US-PGPUB; USPAT	OR	OFF	2005/06/10 16:07
L7	306	5 and 6	US-PGPUB; USPAT	OR	OFF	2005/06/10 16:08
L8	3169	1 near2 2	US-PGPUB; USPAT	OR	OFF	2005/06/10 16:09
L9	126	4 and 8	US-PGPUB; USPAT	OR	OFF	2005/06/10 16:09
L10	36	6 and 9	US-PGPUB; USPAT	OR	OFF	2005/06/10 16:19
L11	90	9 not 10	US-PGPUB; USPAT	OR	OFF	2005/06/10 16:22
L12	37	11 not "oxidizing fluid source"	US-PGPUB; USPAT	OR	OFF	2005/06/10 16:22
S1	65379	"438"/$.ccls.	US-PGPUB; USPAT	OR	OFF	2004/03/31 19:04
S2	0	semiconductor or ic or "integrated circuit" or microelectronic	US-PGPUB; USPAT	OR	OFF	2003/05/29 17:11